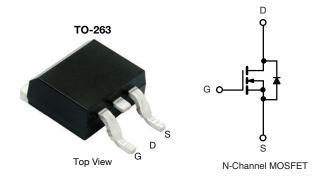


www.vishay.com

Vishay Siliconix

Automotive N-Channel 300 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	300			
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.097			
I _D (A)	35			
Configuration	Single			
Package	TO-263			



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified d
- 100 % R_a and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage		V _{DS}	300	V		
Gate-Source Voltage	V_{GS}	± 20	V			
Continuous Drain Current	T _C = 25 °C	I _D	35			
Continuous Drain Current	T _C = 125 °C		20			
Continuous Source Current (Diode Conduction) a	I _S	120	Α			
Pulsed Drain Current ^b	I _{DM}	75				
Single Pulse Avalanche Current	Single Pulse Avalanche Current		33			
Single Pulse Avalanche Energy L = 0.1 mH		E _{AS}	54	mJ		
Maximum Power Dissipation b	T _C = 25 °C	В	375	W		
iviaximum rower bissipation	T _C = 125 °C	P_{D}	125	VV		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C			

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Ambient PCB Mount c		R_{thJA}	40	°C/W		
Junction-to-Case (Drain)		R_{thJC}	0.4] -C/W		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		300	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5] v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = 300 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 300 V, T _J = 125 °C	-	-	50	μA	
		V _{GS} = 0 V	V _{DS} = 300 V, T _J = 175 °C	-	-	1	mA	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	30	-	-	Α	
		V _{GS} = 10 V	I _D = 10 A	-	0.078	0.097	Ω	
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A, T _J = 125 °C	-	-	0.214		
		V _{GS} = 10 V	I _D = 10 A, T _J = 175 °C	-	-	0.285		
Forward Transconductance b	9fs	V _{DS} = 15 V, I _D = 10 A		-	40	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	4515	5650		
Output Capacitance	Coss	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = 25 V, f = 1 MHz		320	400	pF	
Reverse Transfer Capacitance	C _{rss}			-	146	185	1	
Total Gate Charge ^c	Qg			-	86	130		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 150 \text{ V}, I_D = 9 \text{ A}$	-	16	-	nC	
Gate-Drain Charge ^c	Q _{gd}]		-	28	-		
Gate Resistance	R _g		f = 1 MHz		0.75	1.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}				20	30		
Rise Time ^c	t _r	V_{DD} = 150 V, R_L = 16.7 Ω $I_D \cong$ 9 A, V_{GEN} = 10 V, R_g = 1 Ω		-	40	60]	
Turn-Off Delay Time ^c	t _{d(off)}			-	35	53	ns -	
Fall Time ^c	t _f			-	20	30		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	75	Α	
Forward Voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V		_	0.8	1.5	V	

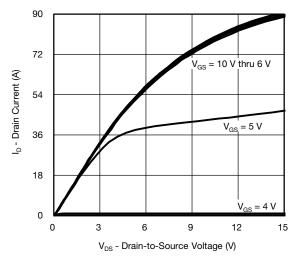
Notes

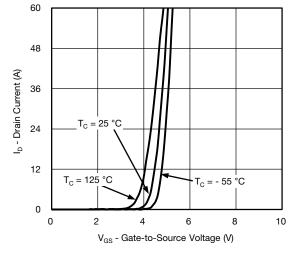
- a. Pulse test; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



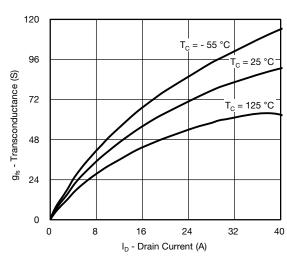
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

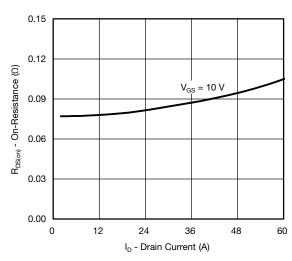




Output Characteristics

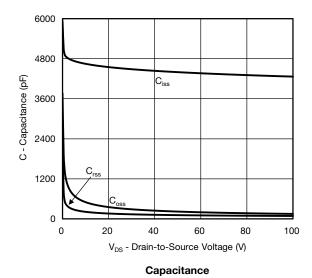


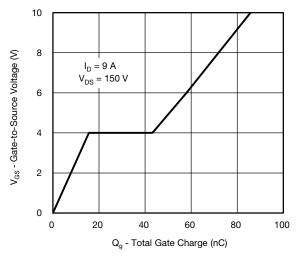




Transconductance

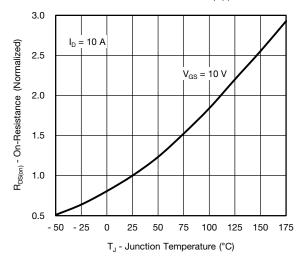
On-Resistance vs. Drain Current

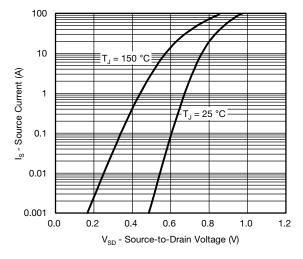




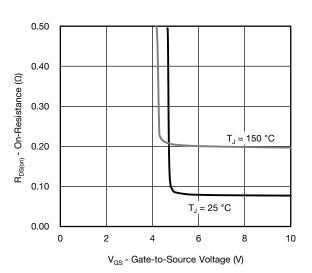


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

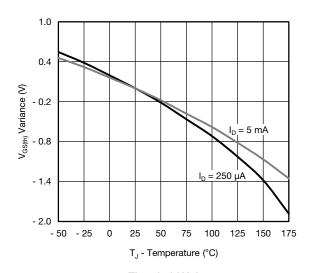




On-Resistance vs. Junction Temperature

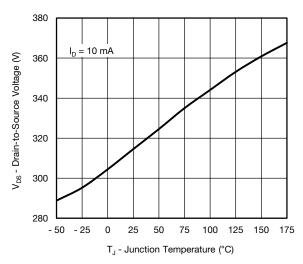


Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



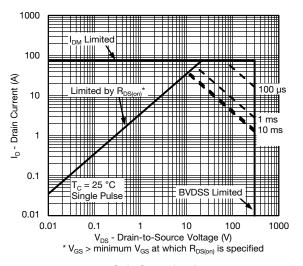


Drain Source Breakdown vs. Junction Temperature

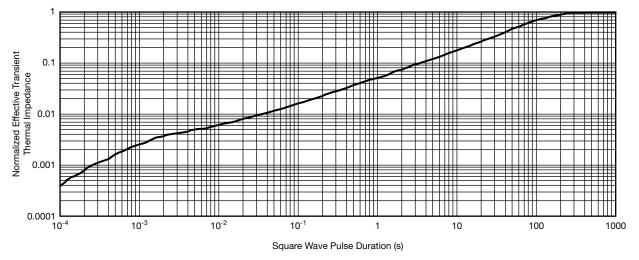
For technical questions, contact: automostech



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



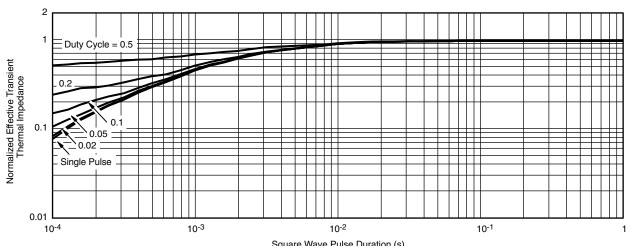
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg266742.



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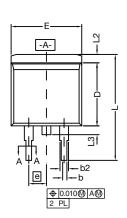
REVISION HISTORY ^a					
REVISION	DATE	DESCRIPTION OF CHANGE			
В	04-Aug-15	Revised R _g minimum limit			

Note

a. As of April 2014



TO-263 (D²PAK): 3-LEAD

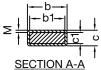








DETAIL A (ROTATED 90°)



⋝:	b b1	ţ
2:	T /////// 5	
	SECTION A.	Ţ

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

DIM.		INC	HES	MILLIMETERS		
		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100) BSC	2.54 BSC		
K		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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